# **ON Semiconductor**

# Is Now



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# 3.3 pF Passive Tunable Integrated Circuits (PTIC)

#### Introduction

ON Semiconductor's PTICs have excellent RF performance and power consumption, making them suitable for any mobile handset or radio application. The fundamental building block of our PTIC product line is a tunable material called ParaScan<sup>™</sup>, based on Barium Strontium Titanate (BST). PTICs have the ability to change their capacitance from a supplied bias voltage generated by the Control IC. The 3.3 pF ultra–high tuning PTICs are available as wafer-level chip scale packages (WLCSP).

#### **Key Features**

- Ultra-High Tuning Range and Operation up to 24 V
- Usable Frequency Range: from 700 MHz to 2.7 GHz
- High Quality Factor (Q) for Low Loss
- High Power Handling Capability
- Compatible with PTIC Control IC TCC-10x, 20x
- WLCSP Package: 0.609 x 0.626 x 0.310 mm (4 bump)
- These devices are Pb-Free and RoHS Compliant

#### **Typical Applications**

- Multi-band, Multi-standard, Advanced and Simple Mobile Phones
- Tunable Antenna Matching Networks
- Tunable RF Filters
- Active Antennas



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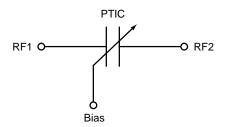


WLCSP4 0.626x0.609 CASE 567LN

#### **MARKING DIAGRAM**



#### **FUNCTIONAL BLOCK DIAGRAM**



**PTIC Functional Block Diagram** 

#### **ORDERING INFORMATION**

| Device        | Package             | Shipping <sup>†</sup>          |
|---------------|---------------------|--------------------------------|
| TCP-4133UB-DT | WLCSP4<br>(Pb-Free) | 4000 Units /<br>7" Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

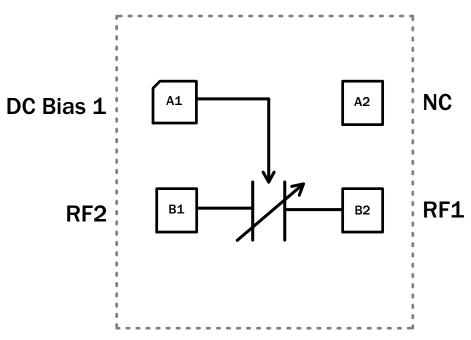


Figure 1. PTIC Functional Block Diagram

**Table 1. SIGNAL DESCRIPTIONS** 

| Ball / Pad Number | Pin Name  | Description       |
|-------------------|-----------|-------------------|
| A1                | DC Bias 1 | DC Bias Voltage   |
| B1                | RF2       | RF Input / Output |
| A2                | NC        | Not Connected     |
| B2                | RF1       | RF Input / Output |

# **TYPICAL SPECIFICATIONS**

#### Representative Performance Data at 25°C

**Table 2. PERFORMANCE DATA** 

| Parameter  | Min   | Тур   | Max   | Units |
|--|-------|-------|-------|-------|
| Operating Bias Voltage                                   | 1.0   |       | 24    | V     |
| Capacitance (V <sub>bias</sub> = 2 V)                    | 2.97  | 3.30  | 3.63  | pF    |
| Capacitance (V <sub>bias</sub> = 24 V)                   | 0.632 | 0.702 | 0.772 | pF    |
| Tuning Range (1 V - 24 V)                                | 4.80  | 5.30  | 6.00  |       |
| Tuning Range (2 V - 24 V)                                | 4.20  | 4.70  | 5.30  |       |
| Leakage Current (WLCSP)                                  |       |       | 0.5   | μΑ    |
| Operating Frequency                                      | 700   |       | 2700  | MHz   |
| Quality Factor @ 700 MHz, 10 V                           |       | 90    |       |       |
| Quality Factor @ 2.4 GHz, 10 V                           |       | 60    |       |       |
| IP3 (V <sub>bias</sub> = 2 V) <sup>[1,3]</sup>           |       | 70    |       | dBm   |
| IP3 (V <sub>bias</sub> = 24 V) <sup>[1,3]</sup>          |       | 80    |       | dBm   |
| 2nd Harmonic (V <sub>bias</sub> = 2 V) <sup>[2,3]</sup>  |       | -65   |       | dBm   |
| 2nd Harmonic (V <sub>bias</sub> = 24 V) <sup>[2,3]</sup> |       | -75   |       | dBm   |
| 3rd Harmonic (V <sub>bias</sub> = 2 V) [2,3]             |       | -40   |       | dBm   |
| 3rd Harmonic (V <sub>bias</sub> = 24 V) [2,3]            |       | -70   |       | dBm   |
| Transition Time (Cmin $\rightarrow$ Cmax) [4]            |       | 80    |       | μs    |
| Transition Time (Cmax → Cmin) [4]                        |       | 70    |       | μs    |

<sup>1.</sup>  $f_1$  = 850 MHz,  $f_2$  = 860 MHz, Pin 25 dBm/Tone 2. 850 MHz, Pin +34 dBm 3. IP3 and Harmonics are measured in the shunt configuration in a 50  $\Omega$  environment 4. RF<sub>IN</sub> and RF<sub>OUT</sub> are both connected to DC ground

#### Representative performance data at 25°C for 3.3 pF WLCSP Package

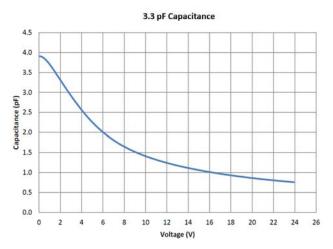


Figure 2. Capacitance

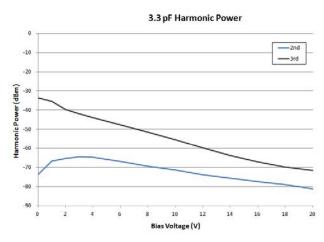


Figure 3. Harmonic Power\*

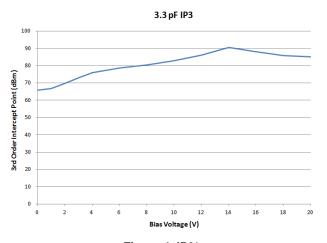


Figure 4. IP3\*

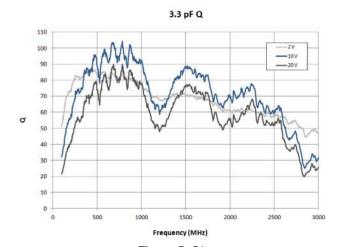


Figure 5. Q\*

**Table 3. ABSOLUTE MAXIMUM RATINGS** 

| Parameter                   | Rating                               | Units |
|-----------------------------|--------------------------------------|-------|
| Input Power                 | +40                                  | dBm   |
| Bias Voltage                | +25 (Note 5)                         | V     |
| Operating Temperature Range | -30 to +85                           | °C    |
| Storage Temperature Range   | -55 to +125                          | °C    |
| ESD – Human Body Model      | Class 1B JEDEC HBM Standard (Note 6) |       |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 5. WLCSP: Recommended Bias Voltage not to exceed 24 V.
- 6. Class 1B defined as passing 500 V, but may fail after exposure to 1000 V ESD pulse.

<sup>\*</sup>Data shown is representative only.

#### ASSEMBLY CONSIDERATIONS AND REFLOW PROFILE

The following assembly considerations should be observed:

#### Cleanliness

These chips should be handled in a clean environment.

#### **Electro-static Sensitivity**

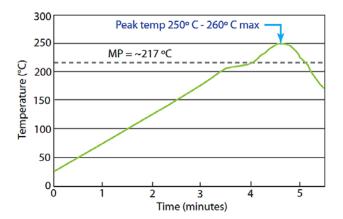
ON Semiconductor's PTICs are ESD Class 1B sensitive. The proper ESD handling procedures should be used.

#### Mounting

The WLCSP PTIC is fabricated for Flip Chip solder mounting. Connectivity to the RF and Bias terminations on the PTIC die is established through SAC305 solder balls with 65  $\mu$ m nominal height (45  $\mu$ m to 85  $\mu$ m height variation). The PTIC die is RoHS-compliant and compatible with lead-free soldering profile.

#### Molding

The PTIC die is compatible for over-molding or under-fill.



This reflow profile is a guideline for Pb-free solder materials. Adjustments to this profile are necessary based on specific process requirements and board size, thickness and density. Not to exceed 260° C for 5 seconds.

Figure 6. Reflow Profile

#### ORIENTATION OF THE PTIC FOR OPTIMUM LOSSES

When configuring the PTIC in your specific circuit design, at least one of the RF terminals must be connected to DC ground. If minimum transition times are required, DC ground on both RF terminals is recommended. To minimize losses, the PTIC should be oriented such that RF2 is at the lower RF impedance of the two RF nodes. A shunt PTIC, for example, should have RF2 connected to RF ground.

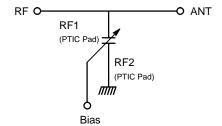


Figure 7. PTIC Orientation Functional Block
Diagram

# **PART NUMBER DEFINITION**

# **Table 4. PART NUMBERS**

|               | Capacitance |       |              |
|---------------|-------------|-------|--------------|
| Part Number   | 2 V         | 24 V  | Package*     |
| TCP-4133UB-DT | 3.30        | 0.733 | 4-bump WLCSP |

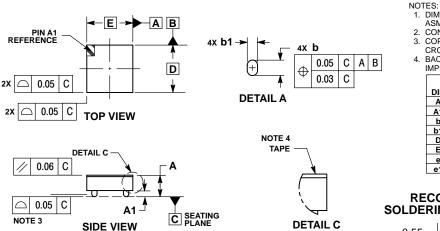
<sup>\*</sup>See PTIC package dimensions on following page.

For information on device numbering and ordering codes, please download the *Device Nomenclature* technical note (TND310/D) from <a href="https://www.onsemi.com">www.onsemi.com</a>.

#### PACKAGE DIMENSIONS

# WLCSP4, 0.626x0.609

CASE 567LN **ISSUE O** 



- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
- COPLANARITY APPLIES TO SPHERICAL
- CROWNS OF SOLDER BALLS.
  4. BACKSIDE TAPE (OPTIONAL) APPLIED TO IMPROVE PIN 1 MARKING.

|     | MILLIMETERS |       |  |
|-----|-------------|-------|--|
| DIM | MIN         | MAX   |  |
| Α   | 0.275       | 0.345 |  |
| A1  | 0.045       | 0.085 |  |
| b   | 0.079       | 0.129 |  |
| b1  | 0.044       | 0.094 |  |
| D   | 0.626 BSC   |       |  |
| E   | 0.609 BSC   |       |  |
| е   | 0.420 BSC   |       |  |
| ۵1  | 0.400 BSC   |       |  |

# RECOMMENDED SOLDERING FOOTPRINT\*

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**BOTTOM VIEW** 

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